

A new crystal structure for (BEDT-TTF)₂SbF₆ and some of its physical properties

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Abstract. A new crystal structure for *bis*(ethylenedithio)tetrathiafulvalene [(BEDT-TTF)₂SbF₆] was determined by single crystal X-ray diffraction. The crystal structure was refined in the *P*1 space group at room temperature. Crystal data for new structure are as follows: triclinic, *a* = 8.670 (2) Å, *b* = 8.664 (2) Å, *c* = 16.842 (5) Å, $\alpha = 89^\circ.29$ (2), $\beta = 90^\circ.71$ (3), $\gamma = 92^\circ.67$ (1), *V* = 1263.64 Å³, *Z* = 2, *D*_x = 2.136 g cm⁻³, (Mo-K α), $\lambda = 0.7107$ Å, *R* = 0.057 for a total of 5517 independent reflections. The donors form a trimerized column, and the band structure calculated by the tight-binding approximation shows band insulator properties. The temperature dependent of the d.c. resistivity shows a semiconducting behaviour with room temperature resistivity along the *c*-axis; $\rho_{290\text{ K}} = 5.6$ ohm cm.

Keywords. Organic conductors; β -(ET)₂PF₆; (ET)₂SbF₆; electrocrystallization.